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Kind regards,

Team Nexperia

PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

Rev. 5 — 18 November 2011

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

PNP Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

#### Table 1. Product overview

Type number	Package	-			Package
	NXP	JEITA	JEDEC	complement	configuration
PDTA114YE	SOT416	SC-75	-	PDTC114YE	ultra small
PDTA114YM	SOT883	SC-101	-	PDTC114YM	leadless ultra small
PDTA114YT	SOT23	-	TO-236AB	PDTC114YT	small
PDTA114YU	SOT323	SC-70	-	PDTC114YU	very small

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

#### **1.3 Applications**

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-50	V
l <sub>O</sub>	output current		-	-	-100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	



**PNP resistor-equipped transistors;** R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	SOT323; SOT416		
1	input (base)	_	
2	GND (emitter)	3	
3	output (collector)	2	1 R1 R2 sym003
SOT883			
1	input (base)		
2	GND (emitter)	1 3	
3	output (collector)	2 Transparent top view	1 R1 R2 sym003

### 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTA114YE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTA114YM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883				
PDTA114YT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTA114YU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

### 4. Marking

Table 5. Marking codes Type number	Marking code <sup>[1]</sup>
PDTA114YE	36
PDTA114YM	DF
PDTA114YT	*29
PDTA114YU	*55

[1] \* = placeholder for manufacturing site code

PDTA114Y\_SER
Product data sheet

**PNP resistor-equipped transistors;** R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 5. Limiting values

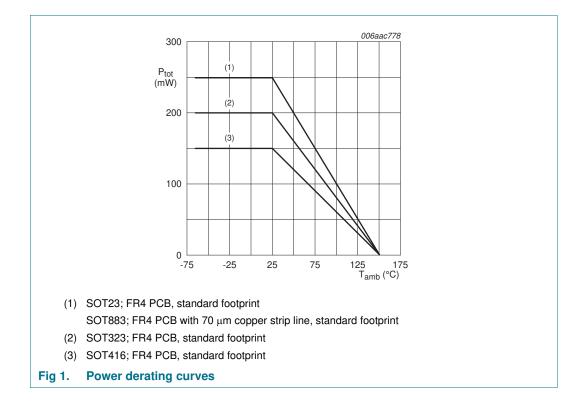
Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-6	V
VI	input voltage				
	positive		-	+6	V
	negative		-	-40	V
lo	output current		-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$	-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTA114YE (SOT416)		[1][2] _	150	mW
	PDTA114YM (SOT883)		[2][3]	250	mW
	PDTA114YT (SOT23)		<u>[1]</u> -	250	mW
	PDTA114YU (SOT323)		[1] -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

### PNP resistor-equipped transistors; R1 = 10 $\overline{k\Omega}$ , R2 = 47 $k\Omega$



### 6. Thermal characteristics

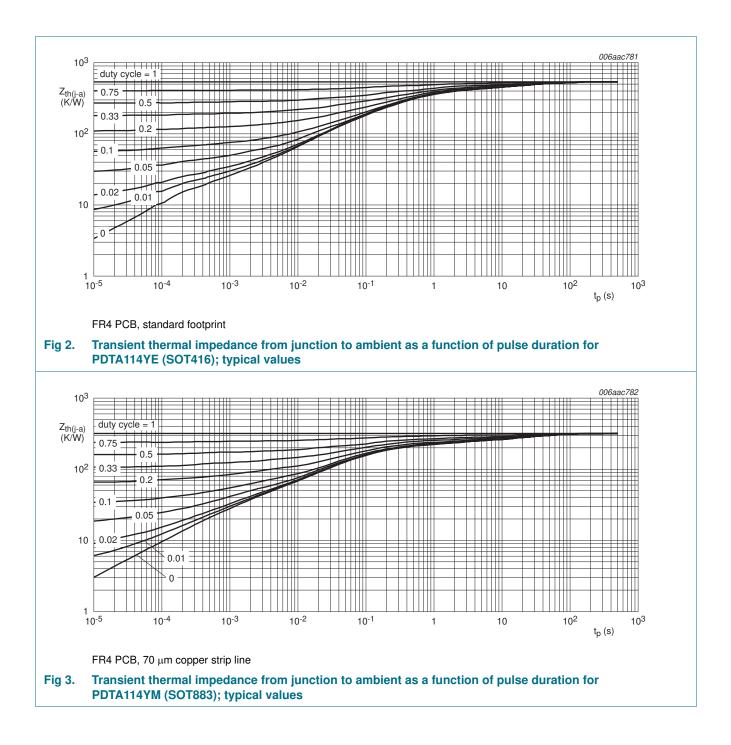
Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	PDTA114YE (SOT416)		<u>[1][2]</u>	-	830	K/W
	PDTA114YM (SOT883)		[2][3]	-	500	K/W
	PDTA114YT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTA114YU (SOT323)		<u>[1]</u> -	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

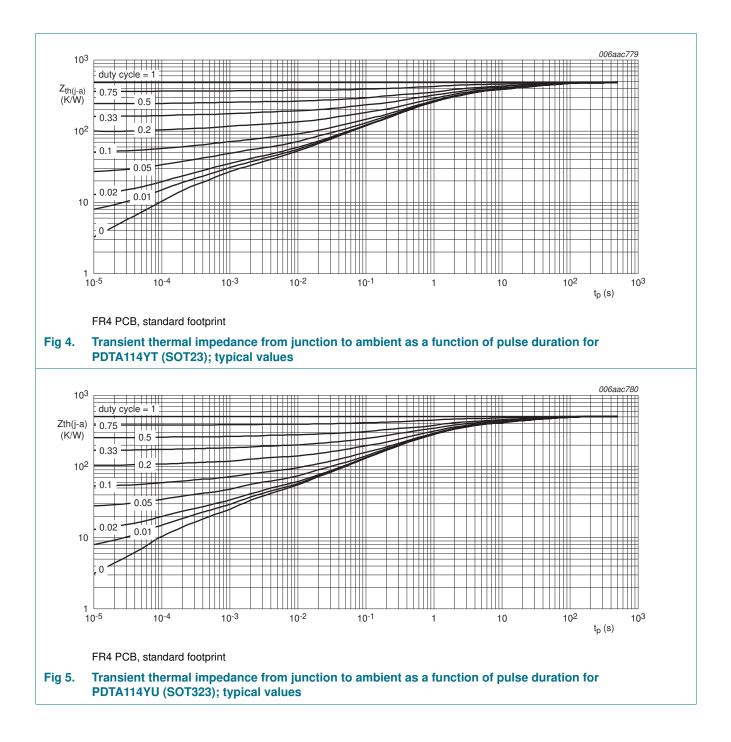
[3] Device mounted on an FR4 PCB with 70  $\mu$ m copper strip line, standard footprint.

# **PDTA114Y series**



# **PDTA114Y series**

PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 



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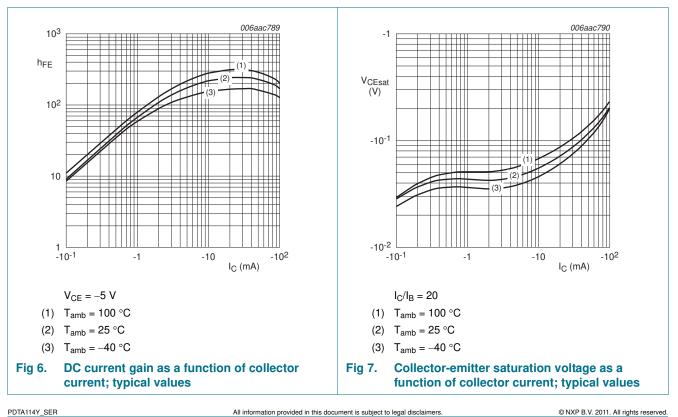
PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

#### **Characteristics** 7.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	-1	μA
	cut-off current	$\label{eq:VCE} \begin{array}{l} V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$	-	-	-5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-150	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_C = -5 \text{ mA}$	100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = -5 \text{ mA}; I_{B} = -0.25 \text{ mA}$	-	-	-100	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \mu\text{A}$	-	-0.7	-0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = -0.3 V; I <sub>C</sub> = -1 mA	-1.4	-0.8	-	V
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{split} V_{CB} &= -10 \text{ V}; \text{ I}_{E} = \text{ i}_{e} = 0 \text{ A}; \\ \text{ f} &= 1 \text{ MHz} \end{split}$	-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; $ [1] f = 100 MHz	-	180	-	MHz

#### [1] Characteristics of built-in transistor

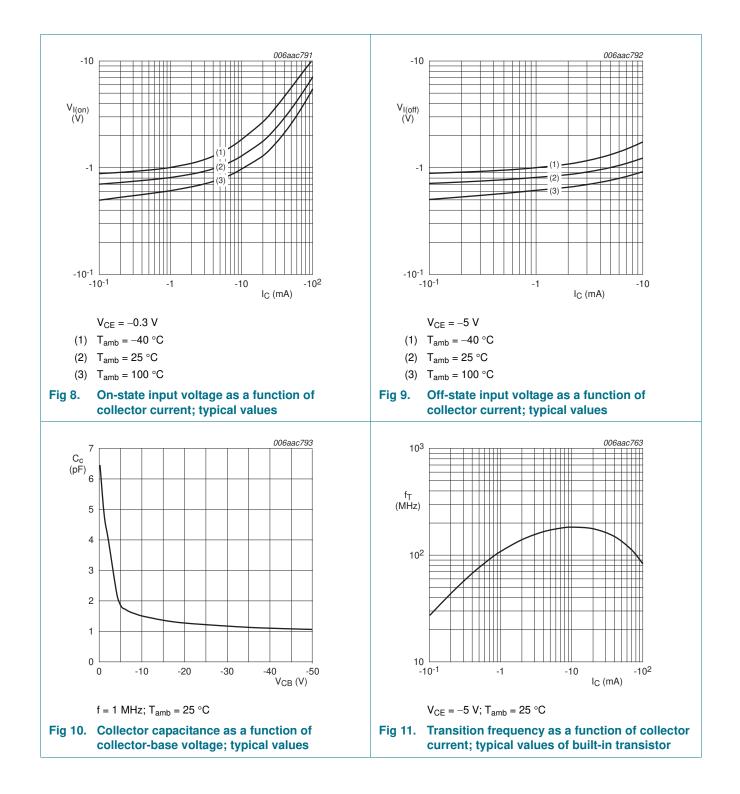
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# **PDTA114Y series**



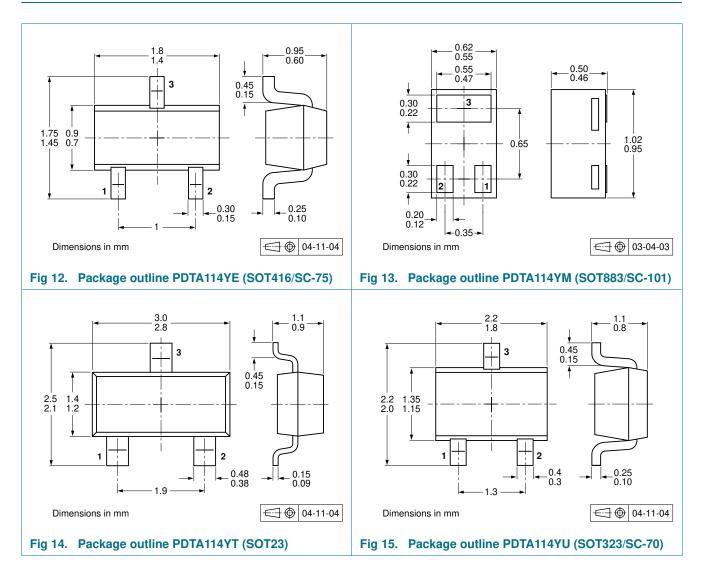
PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



**PNP resistor-equipped transistors;** R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### **10. Packing information**

#### Table 9. Packing methods

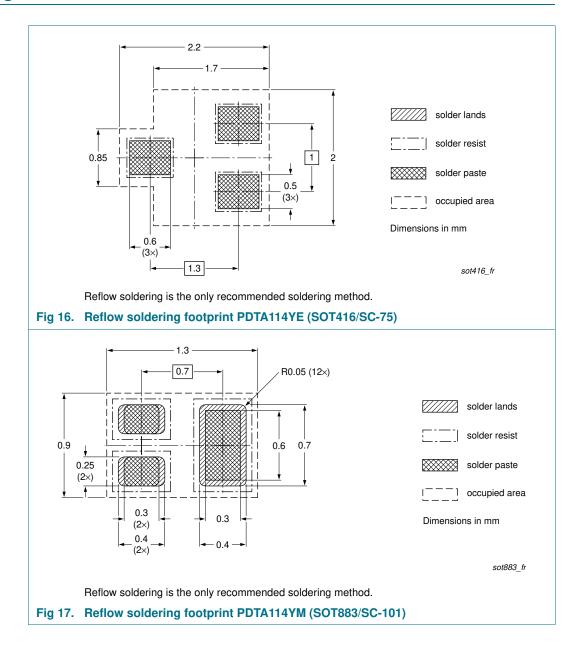
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

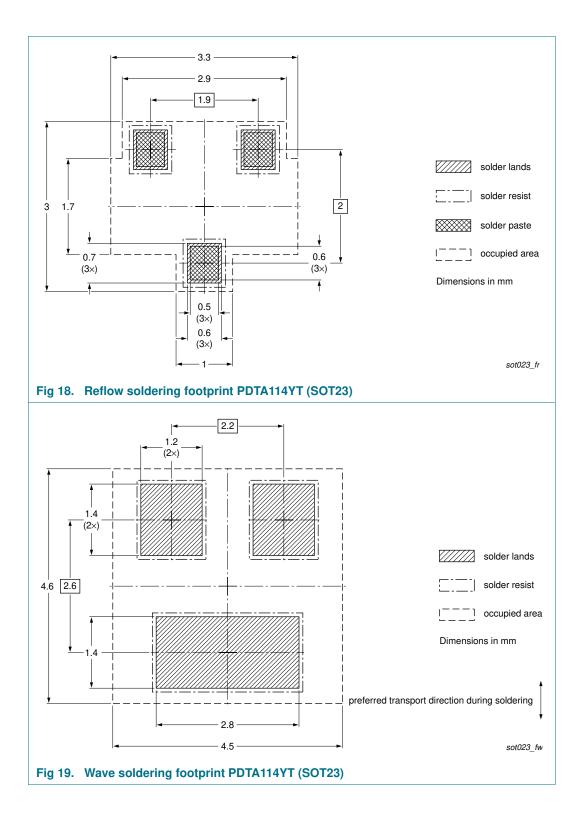
Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTA114YE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTA114YM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTA114YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTA114YU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

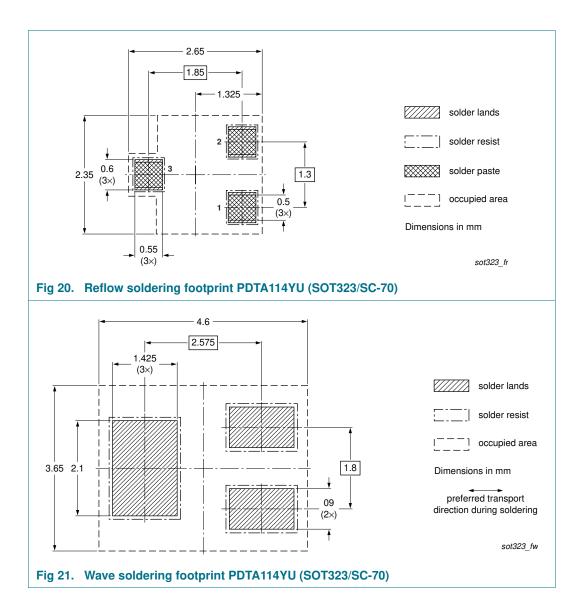
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

### 11. Soldering







### **PNP resistor-equipped transistors;** R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$

### 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PDTA114Y_SER v.5	20111118	Product data sheet	-	PDTA114Y_SERIES v.4		
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>					
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	<ul> <li>Type numbers PDTA114YEF, PDTA114YK and PDTA114YS removed.</li> </ul>					
	<u>Section 1 "Product profile"</u> : updated					
	<u>Section 3 "Ordering information"</u> : added					
	<u>Section 4 "Marking"</u> : updated					
	• Figure 1 to 11: added					
	<ul> <li><u>Section 5 "Limiting values"</u>: updated</li> </ul>					
	<ul> <li><u>Section 6 "Thermal characteristics"</u>: updated</li> </ul>					
	<ul> <li><u>Table 8 "Characteristics</u>": V<sub>i(on)</sub> redefined to V<sub>I(on)</sub> on-state input voltage, V<sub>i(off)</sub> redefined to V<sub>I(off)</sub> off-state input voltage, I<sub>CEO</sub> updated, f<sub>T</sub> added</li> </ul>					
	<u>Section 8 "Test information"</u> : added					
	<ul> <li><u>Section 9 "Package outline"</u>: superseded by minimized package outline drawings</li> </ul>					
	<u>Section 10 "Packing information"</u> : added					
	<ul> <li>Section 11 '</li> </ul>	<u>'Soldering"</u> : added				
	<ul> <li>Section 13</li> </ul>	"Legal information": updated				
PDTA114Y_SERIES v.4	20040802	Product data sheet	-	PDTA114Y_SERIES v.3		
PDTA114Y_SERIES v.3	20030909	Product specification	-	PDTA114Y_SERIES v.2		
PDTA114Y_SERIES v.2	20030411	Product specification	-	PDTA114YEF v.1		
PDTA114YEF v.1	20020515	Product specification	-	_		

### **13. Legal information**

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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PDTA114Y\_SER

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#### PNP resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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# **PDTA114Y series**

**PNP resistor-equipped transistors;** R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

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Date of release: 18 November 2011 Document identifier: PDTA114Y\_SER